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1N3491 thru 1N3495 (SILICON)

V_R — to 1000 V

 $l_0 = 25 A$



Medium-current silicon rectifiers - compact, highly efficient silicon rectifiers for medium-current applications.

MAXIMUM RATINGS

Rating	Symbol	1N3491	IN3492	1N3493	1N3494	1N2495	MR327	MR328	MR330	MR331	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRM(rep) VRM(wkg) VR	50	100	200	300	400	500	600	800	1000	Volta
Non-Repetitive Peak Reverse Voltage (halfwave, single phase, 60 cycle peak)	VRM(non-rep)	100	200	300	400	500	600	720	1000	1200	Volts
RMS Reverse Voltage	v _r	35	70	140	210	280	350	420	560	700	Volts
Average Rectified Forward Current (single phase, resistive load, 60 Hz , see Figure 3) T _C = 130°C	I _O	25							Amp		
Non-Repetitive Peak Surge Current (surge applied at rated load conditions, see Figure 5)	IFM(surge)	300 (for 1/2 cycle)							Amp		
I ² t Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms)	I ² t	375							A _(rms) 2 sec		
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175							°c		

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	,1C	1.2	⁰ C/Watt

MECHANICAL CHARACTERISTICS

CASE: Welded

FINISH: All external surfaces corrosion-resistant and the terminal lead is readily

solderable

POLARITY: CATHODE TO CASE (reverse polarity units are available upon request and

are designated by an "R" suffix

MOUNTING POSITIONS: Any.



Quality Semi-Conductors